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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Bong-Cheol Kim
Serial No. : 10/089,479 ✓ Examiner: Nhu, David
Filed : March 28, 2002 Group Art Unit: 2812
For : APPARATUS AND METHOD FOR FORMING SINGLE
CRYSTALLINE NITRIDE SUBSTRATE USING HYDRIDE
VAPOR PHASE EPITAXY AND LASER BEAM

LETTER

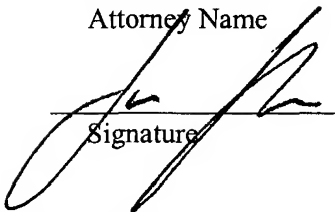
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June 22, 2003

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26,946

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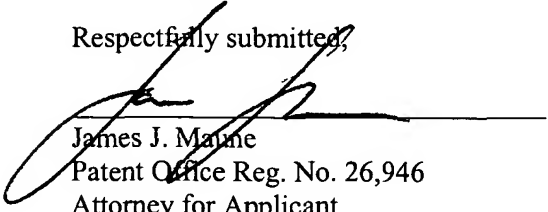
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Sir:

Applicant respectfully requests that the references listed in the PTO 1449 of the Supplemental Information Disclose Statement filed on June 2, 2003, for the above-identified application be disregarded and not made of record as the statement was filed in error.

Respectfully submitted,


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